SGLS154E – NOVEMBER 2000 – REVISED MAY 2010

FAMILY OF NANOPOWER PUSH-PULL OUTPUT COMPARATORS

FEATURES

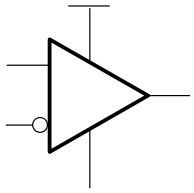
- **Qualified for Automotive Applications**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Low Supply Current . . . 560 nA/Per Channel**
- **Input Common-Mode Range Exceeds the Rails . . . –0.1 V to V_{CC} + 5 V**
- **Supply Voltage Range . . . 2.7 V to 16 V**
- **Reverse Battery Protection Up to 18 V**
- **Push-Pull CMOS Output Stage**
- **Specified Temperature Range**
  - **–40°C to 125°C – Automotive Grade**
- **Ultrasmall Packaging**
  - **5-Pin SOT-23 (TLV3701)**
- **Universal Op-Amp EVM (Reference SLOU060 for more information)**

APPLICATIONS

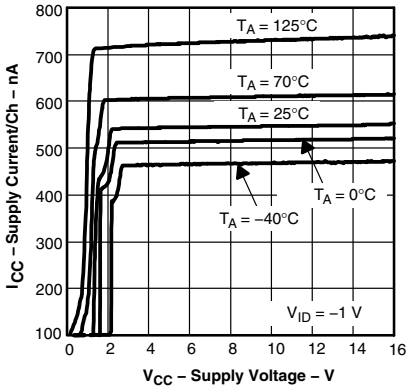
- **Low Power Automotive Electronics**
- **Security Detection Systems**

DESCRIPTION

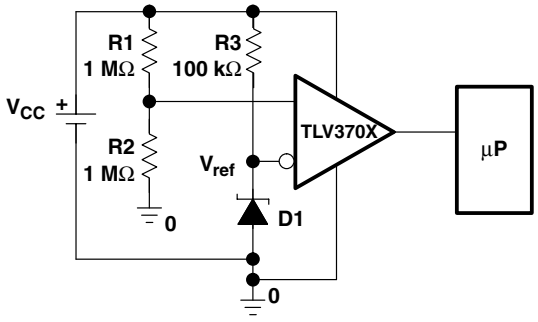
The TLV370x is Texas Instruments' first family of nanopower comparators with only 560 nA per channel supply current, which make this device ideal for low power applications.



SUPPLY CURRENT vs SUPPLY VOLTAGE



high side voltage sense circuit



DESCRIPTION (continued)

The TLV370x has a minimum operating supply voltage of 2.7 V over the extended automotive temperature range (T_A = –40°C to 125°C), while having an input common-mode range of –0.1 to V_{CC} + 5 V. The low supply current makes it an ideal choice for low power applications where quiescent current is the primary concern. Reverse battery protection guards the amplifier from an over-current condition due to improper battery installation. For harsh environments, the inputs can be taken 5 V above the positive supply rail without damage to the device.

Devices are available in SOIC with the singles in the small SOT-23 package. Other package options may be made available upon request.

A SELECTION OF OUTPUT COMPARATORS†

DEVICE	V_{CC} (V)	V_{IO} (μV)	I_{CC}/Ch (μA)	I_{IB} (pA)	t_{PLH} (μs)	t_{PHL} (μs)	t_f (μs)	t_r (μs)	RAIL-TO-RAIL	OUTPUT STAGE
TLV370x	2.5 – 16	250	0.56	80	56	83	22	8	I	PP
TLV340x	2.5 – 16	250	0.47	80	55	30	5	–	I	OD
TLC3702/4	3 – 16	1200	9	5	1.1	0.65	0.5	0.125	–	PP
TLC393/339	3 – 16	1400	11	5	1.1	0.55	0.22	–	–	OD
TLC372/4	3 – 16	1000	75	5	0.65	0.65	–	–	–	OD

† All specifications are typical values measured at 5 V.

TLV3701 AVAILABLE OPTIONS†

T_A	V_{IO}max AT 25°C	PACKAGED DEVICES‡		
		SMALL OUTLINE (D)	SOT-23 (DBV)¶	SYMBOL
-40°C to 125°C	5000 μV	TLV3701QDRQ1§	TLV3701QDBVRQ1	VBCQ

† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.
‡ Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.
§ Product Preview
¶ This package is only available taped and reeled with standard quantities of 3000 pieces per reel.

TLV3702 AVAILABLE OPTIONS

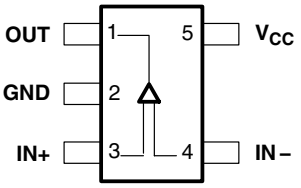
T_A	V_{IO}max AT 25°C	PACKAGED DEVICES	
		SMALL OUTLINE (D)	SYMBOL
–40°C to 125°C	5000 μV	TLV3702QDRQ1	3702Q1

TLV3704 AVAILABLE OPTIONS

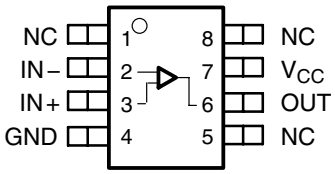
T_A	V_{IO}max AT 25°C	PACKAGED DEVICES
		SMALL OUTLINE (D)
–40°C to 125°C	5000 μV	TLV3704QDRQ1†

† Product Preview

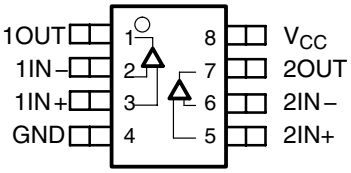
TLV3701
DBV PACKAGE
(TOP VIEW)



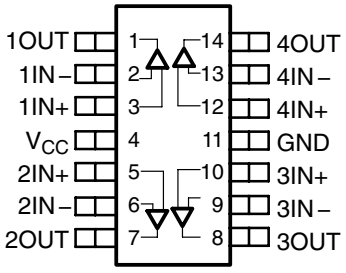
TLV3701
D PACKAGE
(TOP VIEW)



TLV3702
D PACKAGE
(TOP VIEW)



TLV3704
D PACKAGE
(TOP VIEW)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1) . . . . . 17 V
Differential input voltage, V_{ID} . . . . . ±20 V
Input voltage range, V_I (see Notes 1 and 2) . . . . . –0.3 V to V_{CC} + 5 V
Input current range, I_I . . . . . ±10 mA
Output current range, I_O . . . . . ±10 mA
Continuous total power dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A: Q suffix . . . . . –40°C to 125°C
Maximum junction temperature, T_J . . . . . 150°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . . 260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to GND.
2. Input voltage range is limited to 20 V max or V_{CC} + 5 V, whichever is smaller.

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \le 25°C$ POWER RATING	$T_A = 125°C$ POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.6	1022 mW	204.4 mW
DBV (5)	55	324.1	385 mW	77.1 mW

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{CC}	Single supply	2.7	16	V
	Split supply	±1.35	±8	
Common-mode input voltage range, V_{ICR}		–0.1	V_{CC}+5	V
Operating free-air temperature, T_A	Q-suffix	–40	125	°C

electrical characteristics at specified operating free-air temperature, V_{CC} = 2.7 V, 5 V, 15 V (unless otherwise noted)

dc performance

PARAMETER		TEST CONDITIONS	T_A†	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_{IC} = V_{CC}/2$, $R_S = 50\ \Omega$	25°C		250	5000	μV
			Full range			7000	
α_{VIO}	Offset voltage drift		25°C		3		μV/°C
CMRR	Common-mode rejection ratio	V_{IC} = 0 to 2.7 V, $R_S = 50\ \Omega$	25°C	55	72		dB
			Full range	50			
		V_{IC} = 0 to 5 V, $R_S = 50\ \Omega$	25°C	60	76		
			Full range	55			
		V_{IC} = 0 to 15 V, $R_S = 50\ \Omega$	25°C	65	88		
			Full range	60			
A_{VD}	Large-signal differential voltage amplification		25°C		1000		V/mV

† Full range is –40°C to 125°C for Q suffix.

input/output characteristics

PARAMETER		TEST CONDITIONS	T_A†	MIN	TYP	MAX	UNIT
I_{IO}	Input offset current	$V_{IC} = V_{CC}/2$, $R_S = 50\ \Omega$	25°C		20	100	pA
			Full range			1000	
I_{IB}	Input bias current		25°C		80	250	pA
			Full range			2000	
$r_{i(d)}$	Differential input resistance		25°C		300		MΩ
V_{OH}	High-level output voltage	$V_{IC} = V_{CC}/2$, $I_{OH} = 2\ \mu A$, V_{ID} = 1 V	25°C	V_{CC}– 0.08			mV
		$V_{IC} = V_{CC}/2$, $I_{OH} = -50\ \mu A$, V_{ID} = 1 V	25°C	V_{CC}– 320			
			Full range	V_{CC}– 450			
V_{OL}	Low-level output voltage	$V_{IC} = V_{CC}/2$, $I_{OH} = 2\ \mu A$, V_{ID} = –1 V	25°C		8		mV
		$V_{IC} = V_{CC}/2$, $I_{OH} = 50\ \mu A$, V_{ID} = –1 V	25°C		80	200	
			Full range			300	

† Full range is –40°C to 125°C for Q suffix.

electrical characteristics at specified operating free-air temperature, V_{CC} = 2.7 V, 5 V, 15 V (unless otherwise noted) (continued)

power supply

PARAMETER		TEST CONDITIONS		T_A†	MIN	TYP	MAX	UNIT
I_{CC}	Supply current (per channel)	Output state high		25°C		560	800	nA
				Full range			1200	
PSRR	Power supply rejection ratio	V_{IC} = V_{CC}/2 V, No load	V_{CC} = 2.7 V to 5 V	25°C	75	100		dB
				Full range	70			
			V_{CC} = 5 V to 15 V	25°C	85	105		
				Full range	80			

† Full range is –40°C to 125°C for Q suffix.

switching characteristics at recommended operating conditions, V_{CC} = 2.7 V, 5 V, 15 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$t_{(PLH)}$	Propagation response time, low-to-high-level output (see Note 3)	f = 1 kHz, V_{STEP} = 100 mV, C_L = 10 pF, V_{CC} = 2.7 V, V_{IC} = V_{CC}/2	Overdrive = 2 mV		240		µs
			Overdrive = 10 mV		64	150†	
			Overdrive = 50 mV		36		
$t_{(PHL)}$	Propagation response time, high-to-low-level output (see Note 3)		Overdrive = 2 mV		167		
			Overdrive = 10 mV		67	150†	
			Overdrive = 50 mV		37		
t_r	Rise time	C_L = 10 pF, V_{CC} = 2.7 V			7		µs
t_f	Fall time	C_L = 10 pF, V_{CC} = 2.7 V			9		µs

NOTE 3: The response time specified is the interval between the input step function and the instant when the output crosses 1.4 V. Propagation responses are longer at higher supply voltages, refer to Figures 11–16 for further details.

† This limit applies to the TLV3701-Q1 only.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
	Input bias/offset current	vs Free-air temperature	1
V_{OL}	Low-level output voltage	vs Low-level output current	2, 4, 6
V_{OH}	High-level output voltage	vs High-level output current	3, 5, 7
I_{CC}	Supply current	vs Supply voltage	8
		vs Free-air temperature	9
	Output fall time/rise time	vs Supply voltage	10
	Low-to-high level output response for various input overdrives		11, 13, 15
	High-to-low level output response for various input overdrives		12, 14, 16

TYPICAL CHARACTERISTICS

INPUT BIAS/OFFSET CURRENT vs FREE-AIR TEMPERATURE

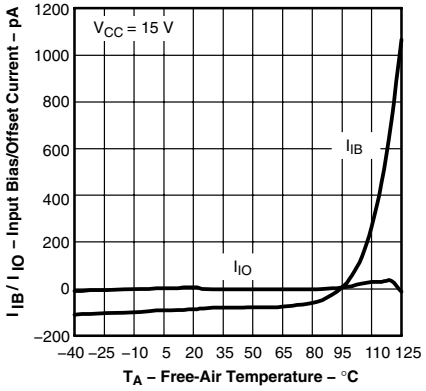


Figure 1

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

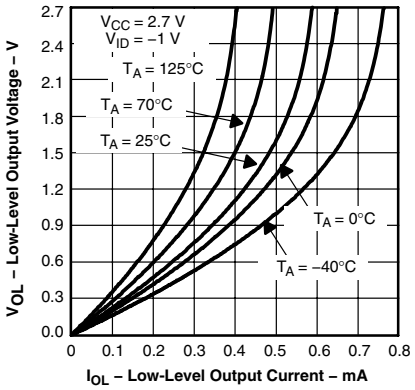


Figure 2

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

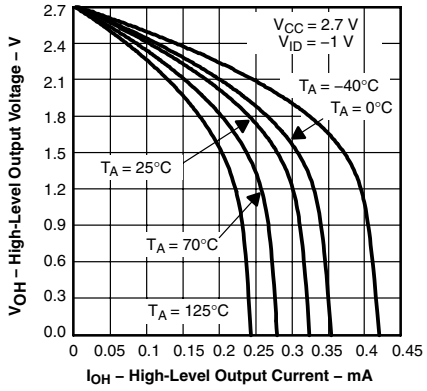


Figure 3

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

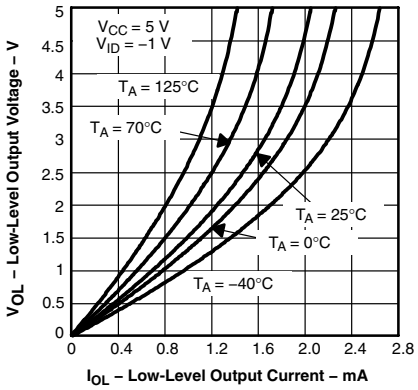


Figure 4

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

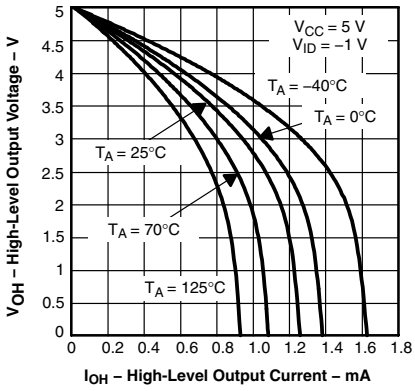


Figure 5

LOW-LEVEL OUTPUT VOLTAGE vs LOW-LEVEL OUTPUT CURRENT

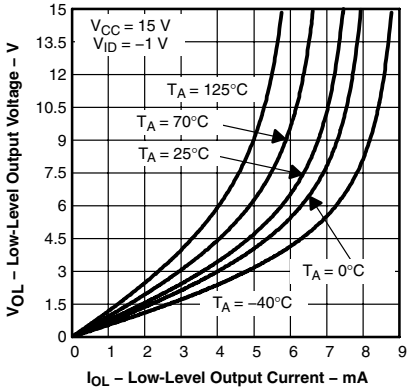


Figure 6

HIGH-LEVEL OUTPUT VOLTAGE vs HIGH-LEVEL OUTPUT CURRENT

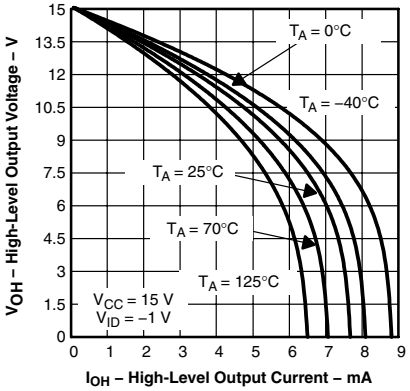


Figure 7

SUPPLY CURRENT vs SUPPLY VOLTAGE

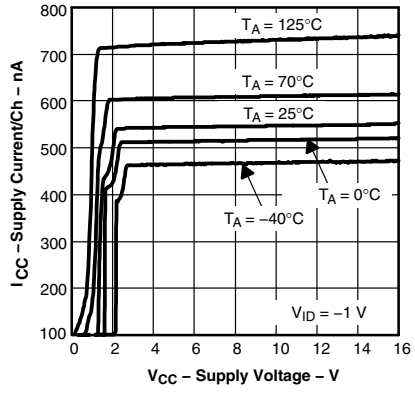


Figure 8

TYPICAL CHARACTERISTICS

SUPPLY CURRENT vs FREE-AIR TEMPERATURE

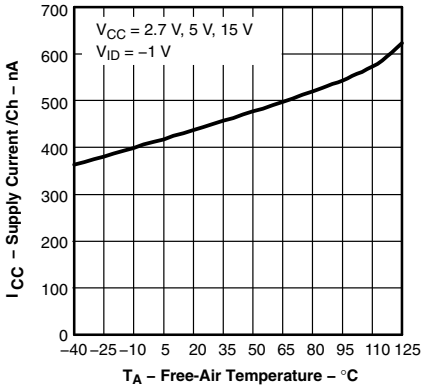


Figure 9

OUTPUT RISE/FALL TIME vs SUPPLY VOLTAGE

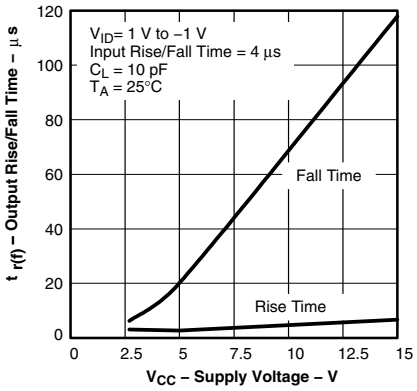


Figure 10

LOW-TO-HIGH OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

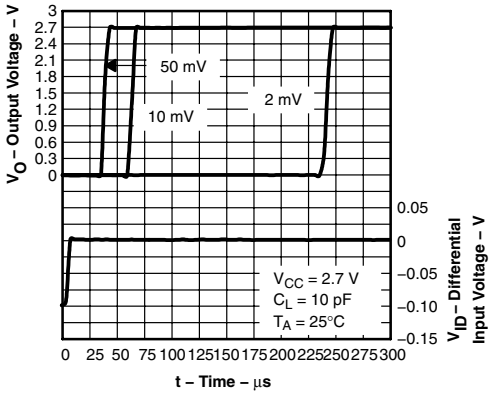


Figure 11

HIGH-TO-LOW LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

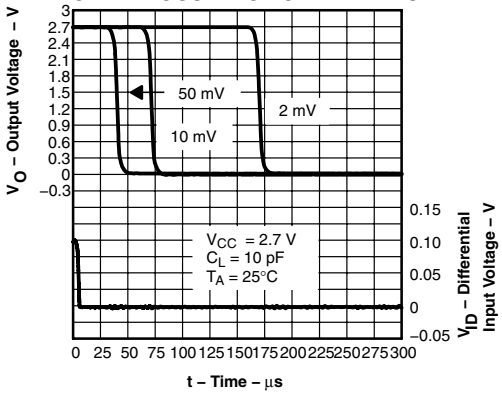


Figure 12

LOW-TO-HIGH LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

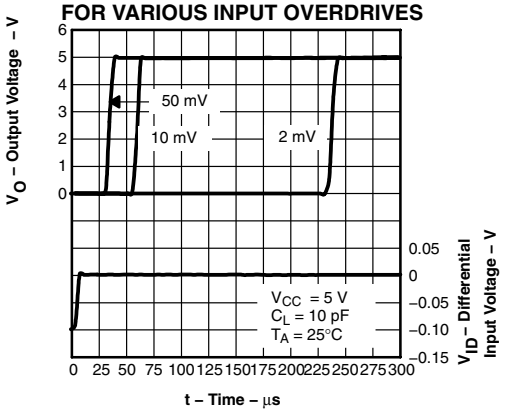


Figure 13

HIGH-TO-LOW LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

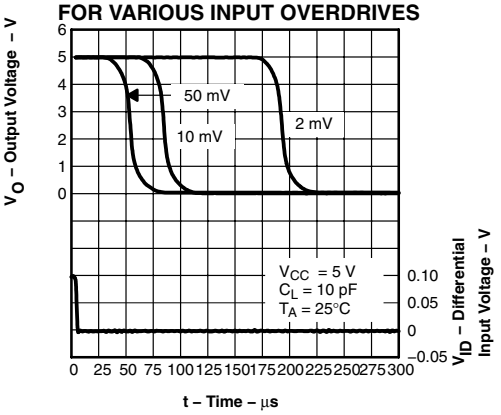


Figure 14

TYPICAL CHARACTERISTICS

LOW-TO-HIGH LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

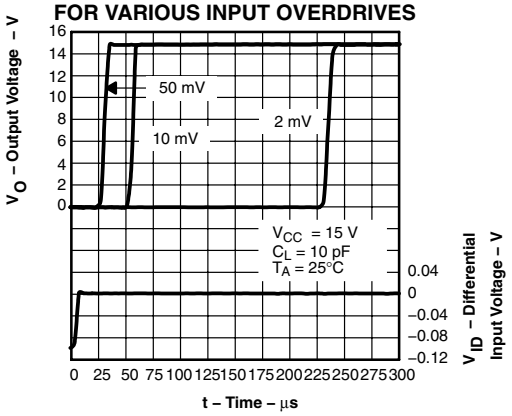


Figure 15

HIGH-TO-LOW LEVEL OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

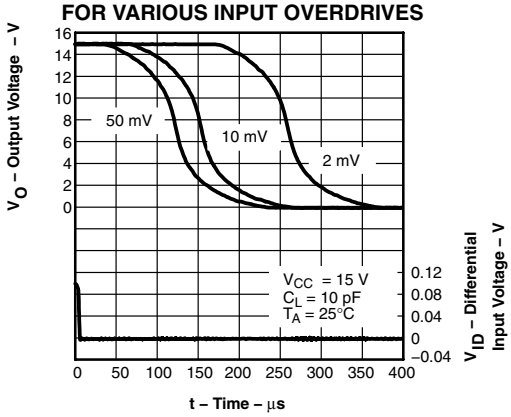


Figure 16

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLV3701QDBVRG4Q1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBCQ	Samples
TLV3701QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBCQ	Samples
TLV3702QDRG4Q1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	3702Q1	Samples
TLV3702QDRQ1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	3702Q1	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

OTHER QUALIFIED VERSIONS OF TLV3701-Q1, TLV3702-Q1 :

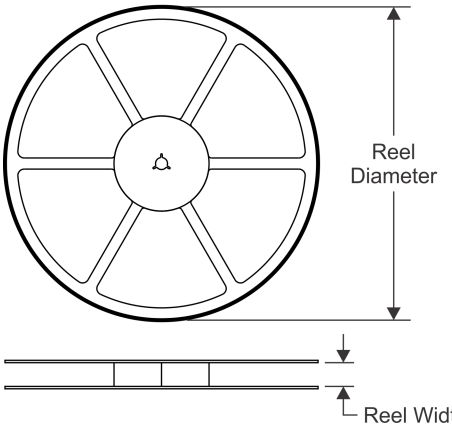
- Catalog: TLV3701, TLV3702
- Enhanced Product: TLV3701-EP

NOTE: Qualified Version Definitions:

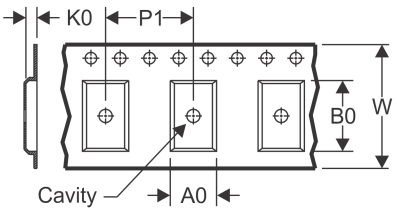
- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

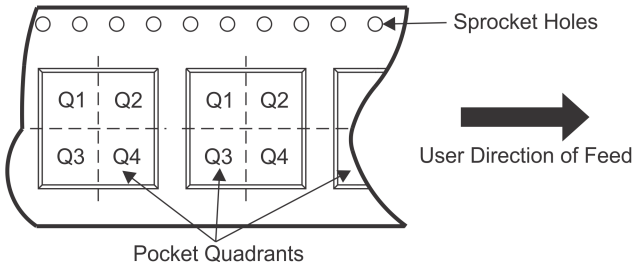


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

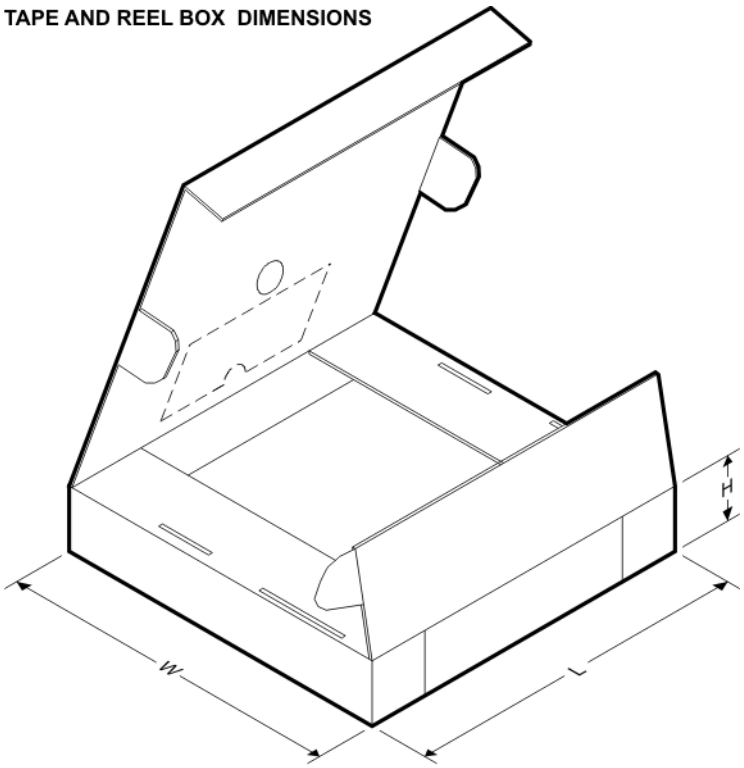
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV3701QDBVRG4Q1	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV3701QDBVRQ1	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3

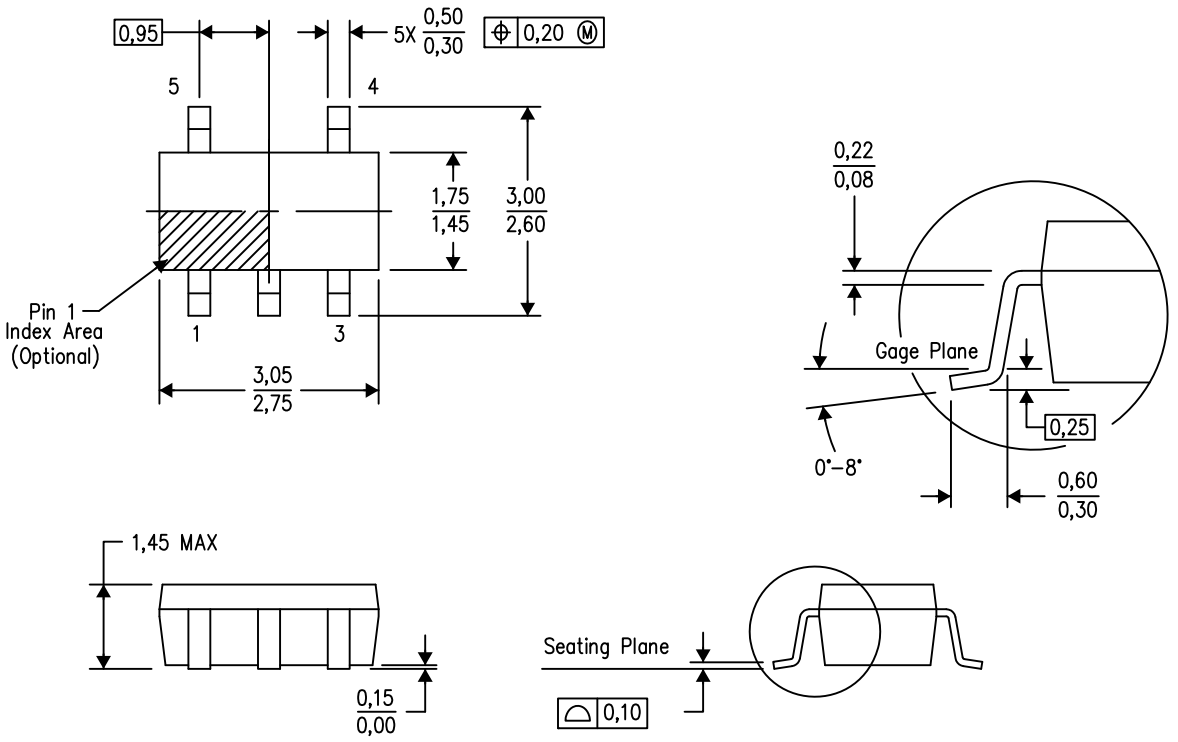
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV3701QDBVRG4Q1	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV3701QDBVRQ1	SOT-23	DBV	5	3000	182.0	182.0	20.0

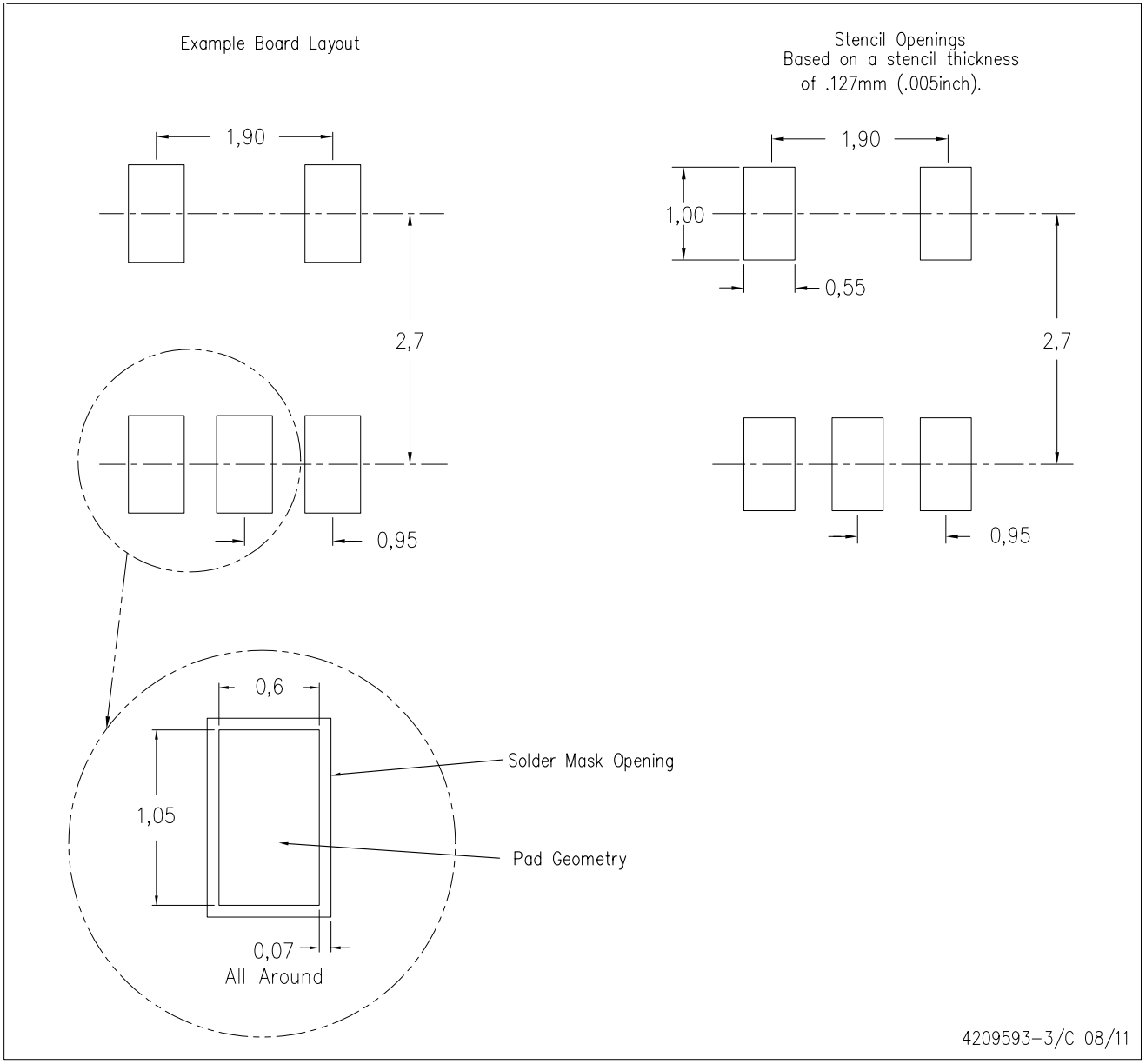
DBV (R–PDSO–G5) PLASTIC SMALL–OUTLINE PACKAGE



4073253–4/N 12/14

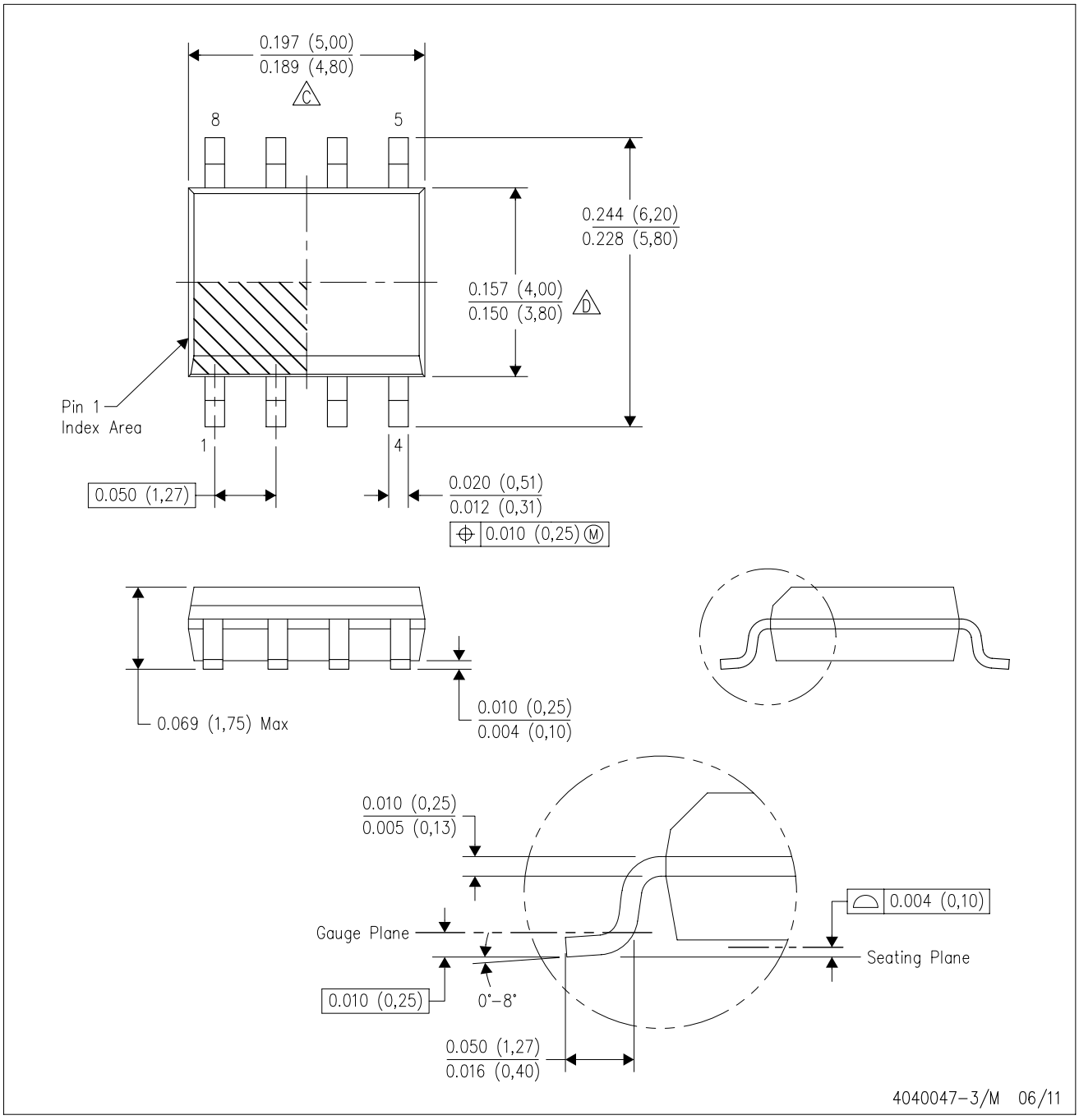
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
D. Falls within JEDEC MO–178 Variation AA.

DBV (R–PDSO–G5) PLASTIC SMALL OUTLINE



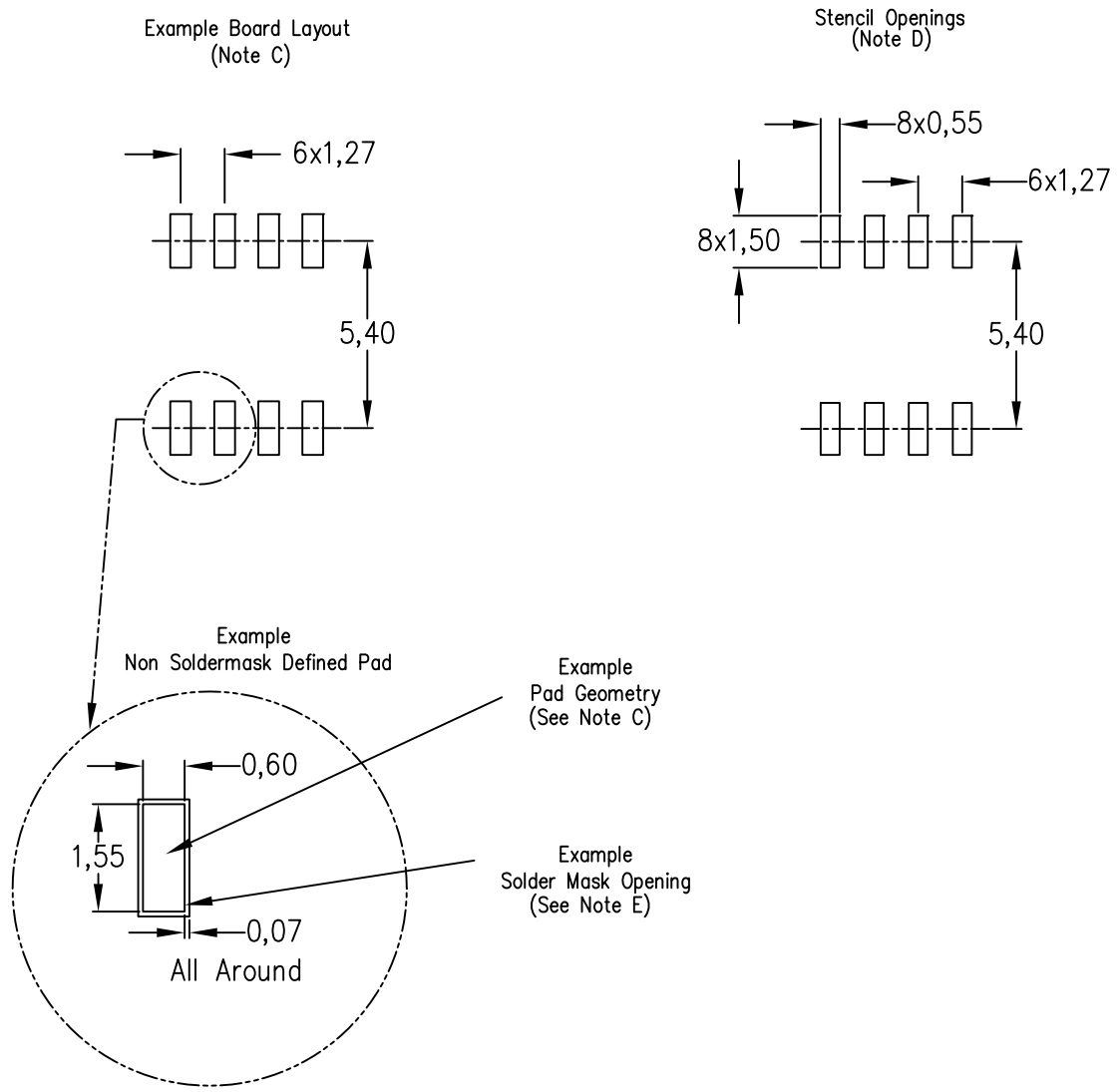
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC–7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC–7525 for other stencil recommendations.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as “components”) are sold subject to TI’s terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI’s terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers’ products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers’ products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI’s goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or “enhanced plastic” are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have ***not*** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		**Applications**	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	**TI E2E Community**	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconnectivity		

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265